# **BC848** series

# 30 V, 100 mA NPN general-purpose transistors

Rev. 07 — 17 November 2009

Product data sheet

### 1. Product profile

### 1.1 General description

NPN general-purpose transistors in Surface Mounted Device (SMD) plastic packages.

Table 1. Product overview

Type number	Package	PNP		
	Nexperia	JEITA	JEDEC	complement
BC848B	SOT23	-	TO-236AB	BC858B
BC848W	SOT323	SC-70	-	BC858W

#### 1.2 Features

- General-purpose transistors
- SMD plastic packages

### 1.3 Applications

■ General-purpose switching and amplification

### 1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	30	V
I <sub>C</sub>	collector current		-	-	100	mA
h <sub>FE</sub>	DC current gain	$V_{CE} = 5 \text{ V};$ $I_{C} = 2 \text{ mA}$				
	BC848B		200	290	450	
	BC848W		110	-	800	



# 2. Pinning information

Table 3. Pinning

	9		
Pin	Description	Simplified outline Symbol	
1	base		
2	emitter	3	
3	collector	1—	
		006aaa144 sym021	

# 3. Ordering information

Table 4. Ordering information

Type number	Package			
	Name	Description	Version	
BC848B	-	plastic surface mounted package; 3 leads	SOT23	
BC848W	SC-70	plastic surface mounted package; 3 leads	SOT323	

# 4. Marking

Table 5. Marking codes

Type number	Marking code <sup>[1]</sup>
BC848B	1K*
BC848W	1M*

- [1] \* = -: made in Hong Kong
  - \* = p: made in Hong Kong
  - \* = t: made in Malaysia
  - \* = W: made in China

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30 V, 100 mA NPN general-purpose transistors

#### **Limiting values** 5.

Table 6. **Limiting values** 

In accordance with the Absolute Maximum Rating System (IEC 60134).

		• • •	,		
Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter	-	30	V
$V_{CEO}$	collector-emitter voltage	open base	-	30	V
$V_{EBO}$	emitter-base voltage	open collector	-	5	V
I <sub>C</sub>	collector current		-	100	mA
I <sub>CM</sub>	peak collector current	$\begin{array}{l} \text{single pulse;} \\ t_p \leq 1 \text{ ms} \end{array}$	-	200	mA
I <sub>BM</sub>	peak base current	$\begin{array}{l} \text{single pulse;} \\ t_p \leq 1 \text{ ms} \end{array}$	-	200	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$	[1]		
	SOT23		-	250	mW
	SOT323		-	200	mW
T <sub>j</sub>	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

### Thermal characteristics

**Product data sheet** 

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j\text{-}a)}$	thermal resistance from junction to ambient	in free air	[1]			
	SOT23		-	-	500	K/W
	SOT323		-	-	625	K/W

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

### 7. Characteristics

Table 8. Characteristics

T<sub>amb</sub> = 25 °C unless otherwise specified.

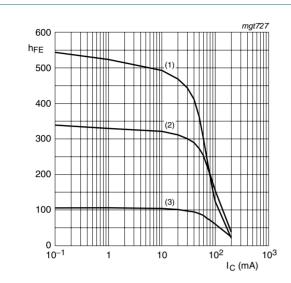
Symbol	Parameter	Conditions	N	lin	Тур	Max	Unit
$I_{CBO}$	collector-base cut-off	$V_{CB} = 30 \text{ V}; I_E = 0 \text{ A}$	-		-	15	nA
	current	$V_{CB} = 30 \text{ V}; I_E = 0 \text{ A};$ $T_j = 150 \text{ °C}$	-		-	5	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{E} = 0 \text{ A}$	-		-	100	nA
h <sub>FE</sub>	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 10 \mu\text{A}$	-		150	-	
		$V_{CE} = 5 \text{ V}; I_{C} = 2 \text{ mA}$					
		BC848B	2	00	290	450	
		BC848W	1	10	-	800	
$V_{\text{CEsat}}$	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	-		90	250	mV
		$I_C = 100 \text{ mA}; I_B = 5 \text{ mA}$	[1] -		200	600	mV
$V_{BEsat}$	base-emitter	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	[2] -		700	-	mV
	saturation voltage	$I_C = 100 \text{ mA}; I_B = 5 \text{ mA}$	[2] -		900	-	mV
$V_{BE}$	base-emitter voltage	$I_C = 2 \text{ mA}; V_{CE} = 5 \text{ V}$	[3] 5	80	660	700	mV
		$I_C = 10 \text{ mA}; V_{CE} = 5 \text{ V}$	[3] _		-	770	mV
f <sub>T</sub>	transition frequency	$V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA};$ f = 100 MHz	1	00	-	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	-		2.5	3	pF
NF	noise figure	$\begin{split} &V_{CE}=5~V;I_{C}=200~\mu\text{A};\\ &R_{S}=2~k\Omega;f=1~k\text{Hz};\\ &B=200~\text{Hz} \end{split}$	-		2	10	dB

<sup>[1]</sup> Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 

<sup>[2]</sup> V<sub>BEsat</sub> decreases by approximately 1.7 mV/K with increasing temperature.

<sup>[3]</sup>  $V_{BE}$  decreases by approximately 2 mV/K with increasing temperature.

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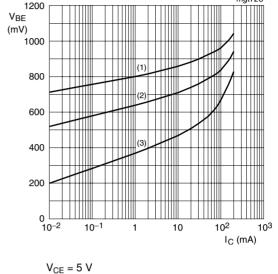
$$V_{CE} = 5 V$$

(1) 
$$T_{amb} = 150 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -55 \, ^{\circ}C$$

BC848B: DC current gain as a function of Fig 1. collector current; typical values



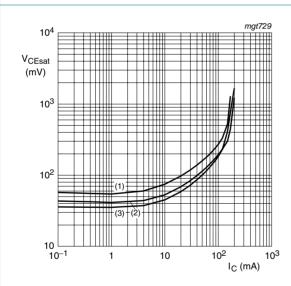
$$V_{CE} = 5 V$$

(1) 
$$T_{amb} = -55 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 150 \, ^{\circ}C$$

Fig 2. BC848B: Base-emitter voltage as a function of collector current; typical values



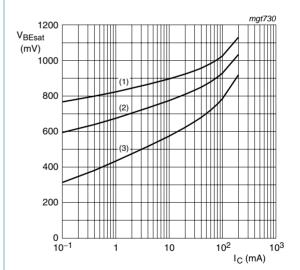
$$I_{C}/I_{B} = 20$$

(1) 
$$T_{amb} = 150 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -55 \, ^{\circ}C$$

BC848B: Collector-emitter saturation voltage Fig 3. as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 10$$

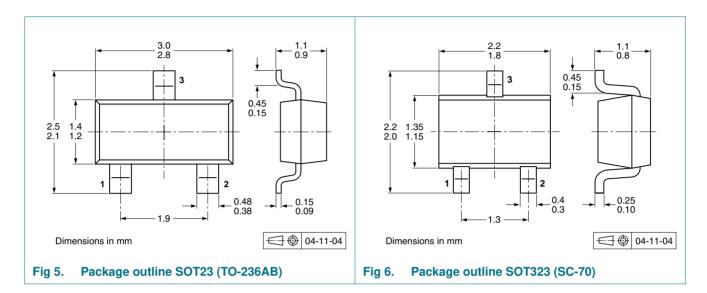
(1) 
$$T_{amb} = -55 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 150 \, ^{\circ}C$$

BC848B: Base-emitter saturation voltage as a Fig 4. function of collector current; typical values

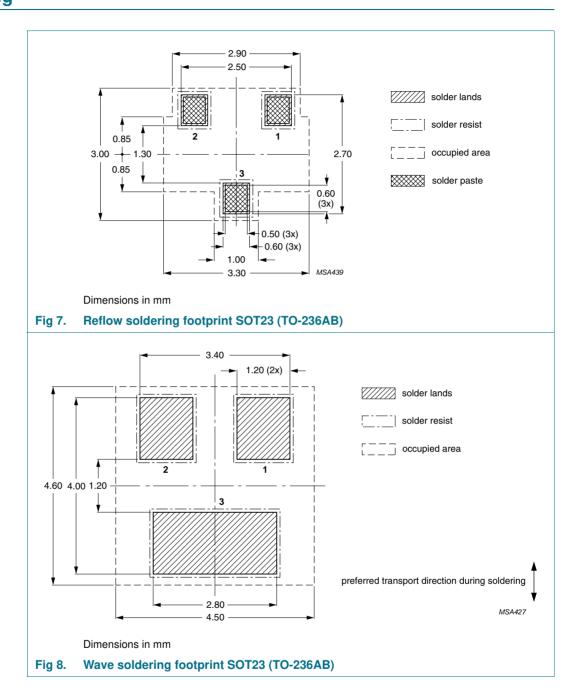
# 8. Package outline

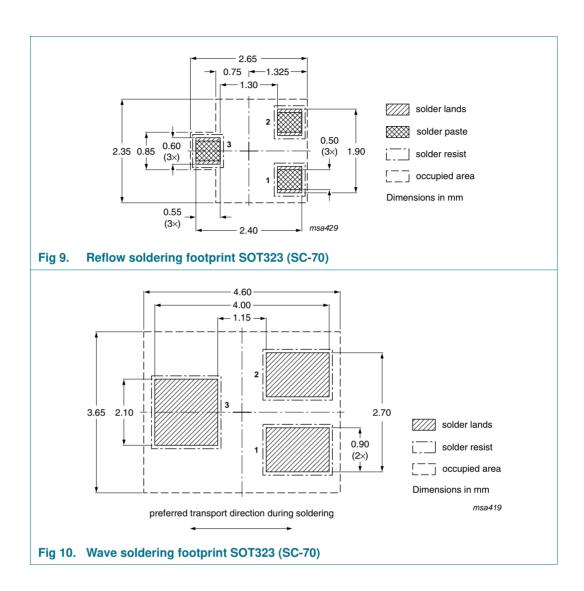


# 9. Packing information

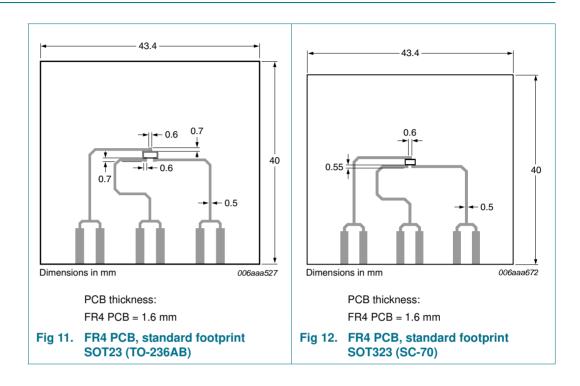
Please refer to packing information on www.nexperia.com.

## 10. Soldering





# 11. Mounting



# 12. Revision history

### Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BC848_SER_7	20091117	Product data sheet	-	BC848_SER_6
Modifications:		was changed to reflect the egal definitions and disclair		
	<ul> <li>Figure 9 "Reflow</li> </ul>	w soldering footprint SOT3	23 (SC-70)": updated	
	• Figure 10 "Wav	e soldering footprint SOT3	23 (SC-70)": updated	
BC848_SER_6	20060203	Product data sheet	-	BC846_BC847_ BC848_5 BC846W_BC847W_ BC848W_4
BC846_BC847_BC848_5	20040206	Product specification	-	BC846_BC847_ BC848_4
BC846W_BC847W_ BC848W_4	20020204	Product specification	-	BC846W_847W_3

## 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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**BC848** series

### **Nexperia**

### 30 V, 100 mA NPN general-purpose transistors

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